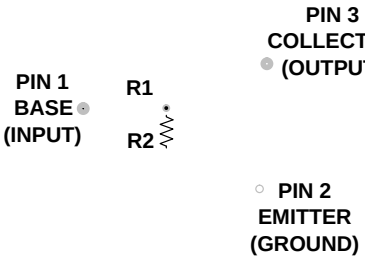
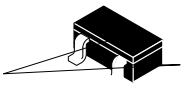
PIN CONNECTIONS



MARKING DIAGRAMS



SC−75
CASE 463
STYLE 1

XXX = Specific Device Code
M = Date Code*
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet

Table 1. ORDERING INFORMATION

Device	Part Marking	Package	Shipping†
MUN2231T1G	8H	SC−59 (Pb−Free)	

Table 2. THERMAL CHARACTERISTICS

Characteristic		Symbol	Max	Unit
THERMAL CHARACTERISTICS (SC−59) (MUN2231)				
Total Device Dissipation		P_D		
T_A = 25°C	(Note 1)		230	mW
	(Note 2)		338	
Derate above 25°C	(Note 1)		1.8	mW/°C
	(Note 2)		2.7	
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{\theta JA}$	540	°C/W
	(Note 2)		370	
Thermal Resistance, Junction to Lead	(Note 1)	$R_{\theta JL}$	264	°C/W
	(Note 2)		287	
Junction and Storage Temperature Range		T_J, T_{stg}	−55 to +150	°C
THERMAL CHARACTERISTICS (SOT−23) (MMUN2231L)				
Total Device Dissipation		P_D		
T_A = 25°C	(Note 1)		246	mW
	(Note 2)		400	
Derate above 25°C	(Note 1)		2.0	mW/°C
	(Note 2)		3.2	
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{\theta JA}$	508	°C/W
	(Note 2)		311	
Thermal Resistance, Junction to Lead	(Note 1)	$R_{\theta JL}$	174	°C/W
	(Note 2)		208	
Junction and Storage Temperature Range		T_J, T_{stg}	−55 to +150	°C
THERMAL CHARACTERISTICS (SC−70/SOT−323) (MUN5231)				
Total Device Dissipation		P_D		
T_A = 25°C	(Note 1)		202	mW
	(Note 2)		310	
Derate above 25°C	(Note 1)		1.6	mW/°C
	(Note 2)		2.5	
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{\theta JA}$	618	°C/W
	(Note 2)		403	
Thermal Resistance, Junction to Lead	(Note 1)	$R_{\theta JL}$	280	°C/W
	(Note 2)		332	
Junction and Storage Temperature Range		T_J, T_{stg}	−55 to +150	°C
THERMAL CHARACTERISTICS (SC−75) (DTC123EE)				
Total Device Dissipation		P_D		
T_A = 25°C	(Note 1)		200	mW
	(Note 2)		300	
Derate above 25°C	(Note 1)		1.6	mW/°C
	(Note 2)		2.4	
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{\theta JA}$	600	°C/W
	(Note 2)		400	
Junction and Storage Temperature Range		T_J, T_{stg}	−55 to +150	°C
THERMAL CHARACTERISTICS (SOT−723) (DTC123EM3)				
Total Device Dissipation		P_D		
T_A = 25°C	(Note 1)		260	mW
	(Note 2)		600	
Derate above 25°C	(Note 1)		2.0	mW/°C
	(Note 2)		4.8	
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{\theta JA}$	480	°C/W
	(Note 2)		205	
Junction and Storage Temperature Range		T_J, T_{stg}	−55 to +150	°C

1. FR−4 @ Minimum Pad.
2. FR−4 @ 1.0 x 1.0 Inch Pad.
3. FR−4 @ 100 mm^2, 1 oz. copper traces, still air.
4. FR−4 @ 500 mm^2, 1 oz. copper traces, still air.

Table 2. THERMAL CHARACTERISTICS

Characteristic		Symbol	Max	Unit
THERMAL CHARACTERISTICS (SOT−1123) (NSBC123EF3)				
Total Device Dissipation T_A = 25°C Derate above 25°C	 (Note 3) (Note 4) (Note 3) (Note 4)	P_D	 254 297 2.0 2.4	 mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 3) (Note 4)	$R_{\theta JA}$	493 421	°C/W
Thermal Resistance, Junction to Lead	(Note 3)	$R_{\theta JL}$	193	°C/W
Junction and Storage Temperature Range		T_J, T_{stg}		

TYPICAL CHARACTERISTICS
MUN2231, MMUN2231L, MUN5231, DTC123E[redacted]EM3

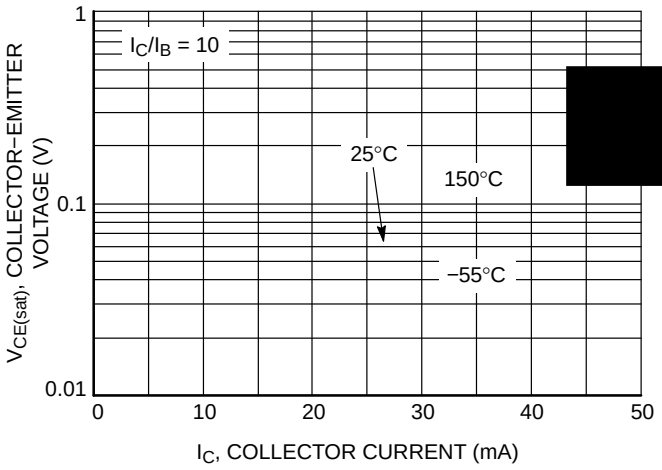


Figure 2. $V_{CE(sat)}$ vs. I_C

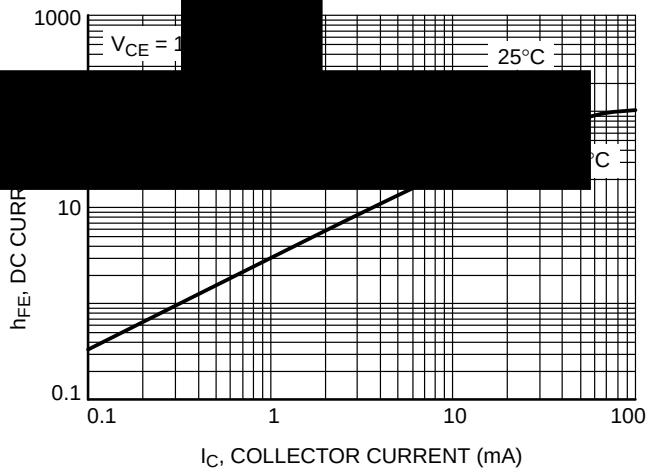


Figure 3. DC Current Gain

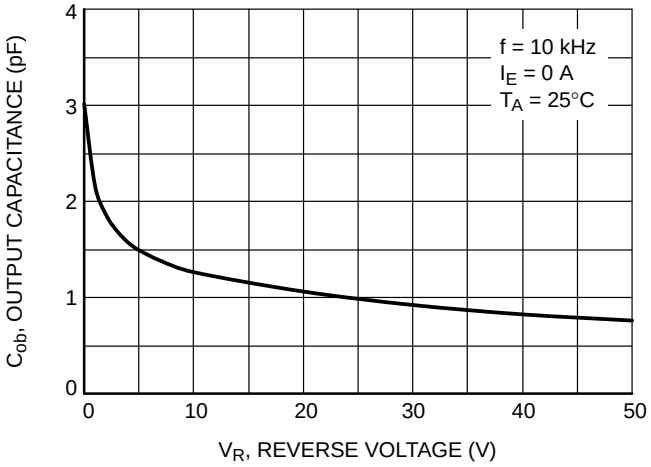


Figure 4. Output Capacitance

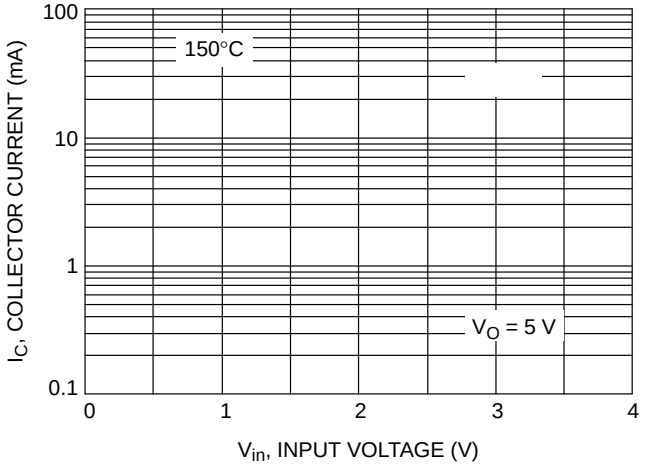


Figure 5. Output Current vs. Input Voltage

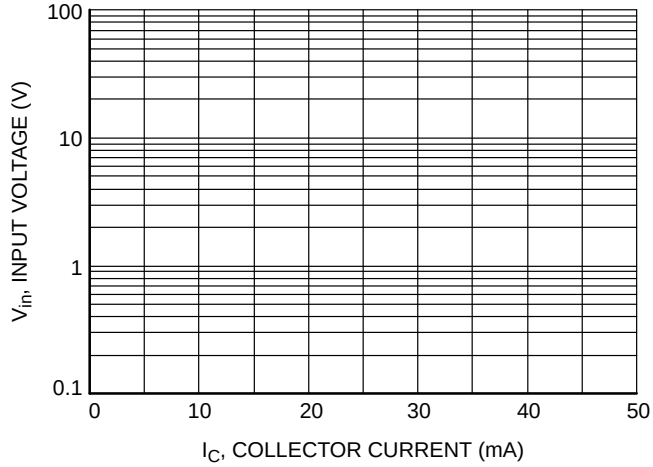
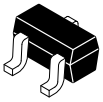


Figure 6. Input Voltage vs. Output Current

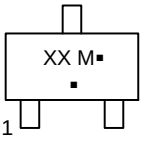


SCALE 4:1

SC−70 (SOT−323)
CASE 419
ISSUE R

DATE 11 OCT 2022

GENERIC
MARKING DIAGRAM



XX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−

STYLE 1:
CANCELLED

STYLE 2:
PIN 1. ANODE
2. N.C.
3. CATHODE

STYLE 3:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 4:
PIN 1. CATHODE
2. CATHODE
3. ANODE

STYLE 5:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 6:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

STYLE 7:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 8:
PIN 1. GATE
2. SOURCE
3. DRAIN

STYLE 9:
PIN 1. ANODE
2. CATHODE
3. CATHODE-ANODE

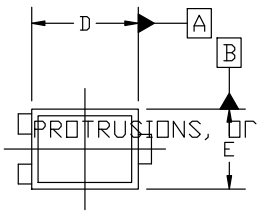
STYLE 10:
PIN 1. CATHODE
2. ANODE
3. ANODE-CATHODE

STYLE 11:
PIN 1. CATHODE
2. CATHODE
3. CATHODE

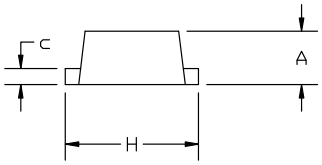
RECOMMEND

SOT−1123 0.80x0.60x0.37, 0.35P
CASE 524AA
ISSUE D

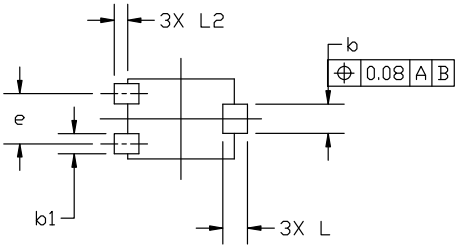
DATE 18 JAN 2024



TOP VIEW



SIDE VIEW



BOTTOM VIEW

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THI , ASH,

 GATE BURRS.

MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.34	0.37	0.40
b	0.15	0.22	0.2
			5
e	0.35	0.38	0.40
H	0.950	1.000	1.050
L	0.185 REF		
L2	0.05	0.10	0.15

GENERIC
MARKING DIAGRAM*

X = Specific Device Code
M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

RECOMMENDED
MOUNTING FOOTPRINT

*

STYLE 1:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 2:
PIN 1. ANODE
2. N/C
3. CATHODE

STYLE 3:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 4:
PIN 1. CATHODE
2. CATHODE
3. ANODE

STYLE 5:
PIN 1. GATE
2. SOURCE
3. DRAIN

SOT−723 1.20x0.80x0.50, 0.40P

GENERIC MARKING